PNP Silicon General Purpose Amplifier Transistor

This PNP transistor is designed for general purpose amplifier applications. This device is housed in the SC-75/SOT-416/SC-90 package which is designed for low power surface mount applications, where board space is at a premium.

Features

- Reduces Board Space
- High h_{FE} , 210–460 (typical)
- Low V_{CE(sat)}, < 0.5 V
- Available in 8 mm, 7-inch/3000 Unit Tape and Reel
- Pb–Free Packages are Available*

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating	Symbol	Value	Unit	
Collector – Emitter Voltage	V _{(BR)CBO}	-60	Vdc	
Collector – Base Voltage	V _{(BR)CEO}	-50	Vdc	
Emitter – Base Voltage	V _{(BR)EBO}	-6.0	Vdc	
Collector Current – Continuous	lc	-100	mAdc	

THERMAL CHARACTERISTICS

Characteristic		Symbol	Max	Unit
Power Dissipation (Note 1)	M	PD	150	mW
Junction Temperature		TJ	150	°C
Storage Temperature Range		T _{stg}	-55 ~ +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.



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ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$)

Characteristic	Symbol	Min	Тур	Max	Unit
Collector–Base Breakdown Voltage ($I_C = -50 \ \mu Adc, I_E = 0$)	V _{(BR)CBO}	-60	-	-	Vdc
Collector–Emitter Breakdown Voltage $(I_{C} = -1.0 \text{ mAdc}, I_{B} = 0)$	V _{(BR)CEO}	-50	-	-	Vdc
Emitter–Base Breakdown Voltage ($I_E = -50 \mu Adc, I_E = 0$)	V _{(BR)EBO}	-6.0	-	-	Vdc
Collector-Base Cutoff Current ($V_{CB} = -30$ Vdc, $I_E = 0$)	Ісво	-	-	-0.5	nA
Emitter–Base Cutoff Current ($V_{EB} = -5.0 \text{ Vdc}, I_B = 0$)	I _{EBO}	-	-	-0.5	μΑ
Collector–Emitter Saturation Voltage (Note 2) ($I_c = -50 \text{ mAdc}, I_B = -5.0 \text{ mAdc}$)	V _{CE(sat)}	-	-	-0.5	Vdc
DC Current Gain (Note 2) (V _{CE} = -6.0 Vdc, I _C = -1.0 mAdc)	h _{FE}	120	-	560	-
Transition Frequency ($V_{CE} = -12 \text{ Vdc}, I_C = -2.0 \text{ mAdc}, f = 30 \text{ MHz}$)	f _T	-	140	-	MHz
Output Capacitance (V _{CB} = –12 Vdc, I _E = 0 Adc, f = 1 MHz)	C _{OB}	- 14	3.5	-	pF
2. Pulse Test: Pulse Width \leq 300 us. D.C. \leq 2%.	2 av				

$(V_{CB} = -12 \text{ Vdc}, I)$	_E = 0 Adc, f = 1 MHz)			5.5	_	pr	
2. Pulse Test: Pulse Width ≤ 300 μs, D.C. ≤ 2%.							
Device		Packag	Package Shipping		ping [†]		
2SA1774		SC-75	5	3000 / Tape & Reel			
2SA1774G		SC-75 3000 / Tape & Reel (Pb-Free)					
2SA1774T1		SC-75	5	3000 / Tape & Reel			
2SA1774T1G		SC-75 3000 / Tape & Reel (Pb-Free)					

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL ELECTRICAL CHARACTERISTICS



PACKAGE DIMENSIONS

SC-75/SOT-416 CASE 463-01 ISSUE F



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